

## TPS2559 Precision Adjustable Current-Limited Power-Distribution Switch

### 1 Features

- 2.5 to 6.5 V Operating Range
- Adjustable 1.2 to 4.7 A  $I_{(LIMIT)}$  ( $\pm 4.4\%$  at 4.7 A)
- 3.5  $\mu\text{s}$  Short Circuit Shutoff (Typical)
- 13-m $\Omega$  High-Side MOSFET
- 2- $\mu\text{A}$  Maximum Standby Supply Current
- Built-in Soft-Start
- 8 kV / 15 kV System-Level ESD Capable
- UL 2367 Recognition Pending

### 2 Applications

- USB Ports/Hubs
- Digital TV
- Set-Top Boxes
- VOIP Phones

### 3 Description

The TPS2559 power-distribution switch is intended for applications where a low resistance, precision current limit switch is required or heavy capacitive loads are encountered. The TPS2559 provides up to 5.5 A of continuous load current with a precise current limit set by a single resistor to ground. Output current is maintained at a safe level by switching into a constant-current mode when the output load exceeds the current-limit threshold. During overload events the output current is limited to the level set by  $R_{(LIMIT)}$ . If a persistent overload occurs, the device goes into thermal shutoff to prevent damage to the TPS2559.

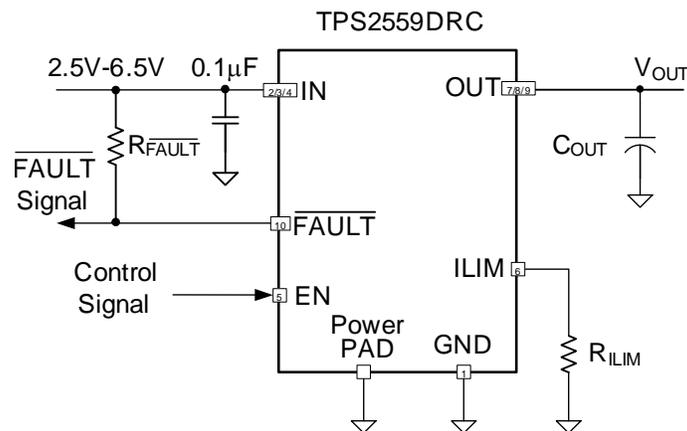
The power-switch rise and fall times are controlled to minimize current surges during turn on or off. The  $\overline{\text{FAULT}}$  logic output asserts low during overcurrent or overtemperature conditions.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS2559	VSON (10)	3.00mm x 3.00mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

### 4 Simplified Schematic



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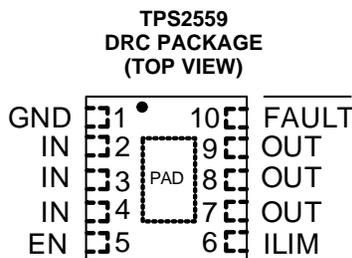
## 5 Revision History

DATE	REVISION	NOTES
June 2014	*	Initial release.

## 6 Device Comparison Table

Device	Operation Range (V)	OCP Mode	ICONT. Adj. Range (A)	$R_{DS(on)}$ (m $\Omega$ )	$I_{OS}$ tolerance	Package SON-8 (DRB) SOT-23 (DBV) SON-10 (DRC) SON-6 (DRV)
TPS2559	2.5 - 6.5	Auto Retry	5.5	13	$\pm 4.4\%$ at 4.7A	DRC
TPS2552/3	2.5 - 6.5	Auto Retry	1.2	85 (DBV) 100 (DRV)	$\pm 6\%$ at 1.7A	DBV DRV
TPS2552/3-1	2.5 - 6.5	Latch Off	1.2	85 (DBV) 100 (DRV)	$\pm 6\%$ at 1.7A	DBV DRV
TPS2554/5 (Dual Adjustable)	4.5 - 5.5	Auto Retry	2.5	73	$\pm 9.7\%$ at 2.8A	DRC
TPS2556/7	2.5 - 6.5	Auto Retry	5	22	$\pm 6.5\%$ at 4.5A	DRB
TPS2560/61 (Dual Channels)	2.5 - 6.5	Auto Retry	2.5	44	$\pm 7.5\%$ at 2.8A	DRC
TPS2560A/61A (Dual Channels)	2.5 - 6.5	Auto Retry	2.5	44	2.1A to 2.5A including $\pm 1\% R_{(ILIM)}$	DRC
TPS25200 (With OVP protection)	2.5 - 6.5 (Withstand up to 20V)	Auto Retry	2.5	60	$\pm 6\%$ at 2.9A	DRV

## 7 Pin Configuration and Functions



### Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
GND	1		Ground connection, connect externally to PowerPAD
IN	2,3,4	I	Input voltage, connect a 0.1 $\mu$ F or greater ceramic capacitor from IN to GND as close to the IC as possible.
EN	5	I	Enable input, logic high turns on power switch
ILIM	6	O	External resistor used to set current-limit threshold; recommended. $24.9 \text{ k}\Omega \leq R_{(ILIM)} \leq 100 \text{ k}\Omega$ .
OUT	7,8,9	O	Power-switch output
$\overline{\text{FAULT}}$	10	O	Active-low open-drain output, asserted during over-current or overtemperature conditions.
PowerPAD™	PAD		Internally connected to GND; used to heat-sink the part to the circuit board traces. Connect PowerPAD to GND pin externally.

## 8 Specifications

### 8.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup> <sup>(2)</sup>

		MIN	MAX	UNIT
Voltage range	IN, OUT, EN, ILIM, $\overline{\text{FAULT}}$	-0.3	7	V
	IN to OUT	-7	7	V
Continuous output current, I <sub>OUT</sub>	OUT	Internally Limited		mA
Continuous $\overline{\text{FAULT}}$ sink current		20		mA
ILIM source current		Internally Limited		mA
Maximum junction temperature, T <sub>J</sub>		-40 to OTSD2		°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Voltages are referenced to GND unless otherwise noted.

### 8.2 Handling Ratings

		MIN	MAX	UNIT
T <sub>stg</sub>	Storage temperature range	-65	150	°C
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>		kV
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>		V
		System Level (Contact/Air) <sup>(3)</sup>		kV

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.
- (3) Surges per EN61000-4-2, 1999 applied between USB and output ground of the TPS2559EVM ([SLUUB15](#)) evaluation module (documentation available on the Web.) These were the test levels, not the failure threshold.

### 8.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V <sub>IN</sub>	Input voltage, IN	2.5	6.5	V
V <sub>EN</sub>	Input voltage, EN	0	6.5	V
I <sub>OUT</sub>	Continuous output current of OUT		5.5	A
	Continuous $\overline{\text{FAULT}}$ sink current		10	mA
R <sub>(ILIM)</sub>	Recommended resistor limit range <sup>(1)</sup>	24.9	100	kΩ
T <sub>J</sub>	Operating junction temperature	-40	125	°C

- (1) R<sub>(ILIM)</sub> is the resistor from ILIM pin to GND and ILIM pin can be shorted to GND.

### 8.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TPS2559	UNIT
		DRC (10 PINS)	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	40.6	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	45.5	
R <sub>θJB</sub>	Junction-to-board thermal resistance	15.9	
ψ <sub>JT</sub>	Junction-to-top characterization parameter	0.4	
ψ <sub>JB</sub>	Junction-to-board characterization parameter	15.7	
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	2.8	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

## 8.5 Electrical Characteristics

Conditions are  $-40^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C}$ ,  $2.5\text{ V} \leq V_{\text{IN}} \leq 6.5\text{ V}$ ,  $V_{(\text{EN})} = V_{\text{IN}}$ ,  $R_{(\text{ILIM})} = 49.9\text{k}\Omega$ . Positive current are into pins. Typical value is at  $25^{\circ}\text{C}$ . All voltages are with respect to GND (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>POWER SWITCH</b>						
$R_{\text{DS(on)}}$	Input - Output Resistance <sup>(1)</sup>	$T_J = 25^{\circ}\text{C}$		13	16	m $\Omega$
		$-40^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C}$			21	
<b>ENABLE INPUT EN</b>						
	EN turn on/off threshold		0.66		1.1	V
	Hysteresis			55 <sup>(2)</sup>		mV
$I_{(\text{EN})}$	Input current	$V_{(\text{EN})} = 0\text{ V}$ or $V_{(\text{EN})} = 6.5\text{ V}$	-1		1	$\mu\text{A}$
<b>CURRENT LIMIT</b>						
$I_{\text{OS}}$	OUT short circuit current limit	$R_{(\text{ILIM})} = 24.9\text{ k}\Omega$	4490	4731	4900	mA
		$R_{(\text{ILIM})} = 44.2\text{ k}\Omega$	2505	2665	2775	
		$R_{(\text{ILIM})} = 49.9\text{ k}\Omega$	2215	2360	2460	
		$R_{(\text{ILIM})} = 61.9\text{ k}\Omega$	1780	1902	1990	
		$R_{(\text{ILIM})} = 100\text{ k}\Omega$	1080	1176	1245	
		ILIM pin short to GND ( $R_{(\text{ILIM})} = 0$ )	5860	6650	7460	
<b>SUPPLY CURRENT</b>						
$I_{(\text{IN\_OFF})}$	Disabled, IN supply current	$V_{(\text{EN})} = 0\text{ V}$ , No load on OUT		0.1	2	$\mu\text{A}$
$I_{(\text{IN\_ON})}$	Enabled, IN supply current	$R_{(\text{ILIM})} = 100\text{ k}\Omega$ , no load on OUT		97	125	$\mu\text{A}$
		$R_{(\text{ILIM})} = 24.9\text{ k}\Omega$ , no load on OUT		107	135	
$I_{(\text{REV})}$	Reverse leakage current	$V_{\text{OUT}} = 6.5\text{ V}$ , $V_{\text{IN}} = 0\text{ V}$ , $T_J = 25^{\circ}\text{C}$ , Measure $I_{\text{OUT}}$		0.01	1	$\mu\text{A}$
<b>UNDERVOLTAGE LOCKOUT</b>						
$V_{\text{UVLO}}$	IN rising UVLO threshold voltage		2.36		2.45	V
	Hysteresis			35 <sup>(2)</sup>		mV
<b>FAULT</b>						
$V_{\text{OL}}$	Output low voltage	$I_{\text{FAULT}} = 1\text{ mA}$			180	mV
	Off-state leakage	$V_{\text{FAULT}} = 6.5\text{ V}$			1	$\mu\text{A}$
<b>THERMAL SHUTDOWN</b>						
OTSD2	Thermal shutdown threshold		155			$^{\circ}\text{C}$
OTSD1	Thermal shutdown threshold in current-limit		135			
	Hysteresis			20 <sup>(2)</sup>		

(1) Pulse-testing techniques maintain junction temperature close to ambient temperature. Thermal effects must be taken into account separately

(2) These parameters are provided for reference only, and don't constitute part of TI's published device specifications for purposes of TI's product warranty.

## 8.6 Timing Requirements

Conditions are  $-40^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C}$ ,  $2.5\text{ V} \leq V_{\text{IN}} \leq 6.5\text{ V}$ ,  $V_{(\text{EN})} = V_{\text{IN}}$ ,  $R_{(\text{ILIM})} = 49.9\text{k}\Omega$ . Positive current are into pins. Typical value is at  $25^{\circ}\text{C}$ . All voltages are with respect to GND (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
<b>POWER SWITCH</b>							
$t_r$	OUT voltage rise time	$V_{\text{IN}} = 6.5\text{ V}$	2.6	3.65	5.2	ms	
		$V_{\text{IN}} = 2.5\text{ V}$	1.3	2.6	3.9		
$t_f$	OUT voltage fall time	$V_{\text{IN}} = 6.5\text{ V}$	0.7	0.95	1.3		
		$V_{\text{IN}} = 2.5\text{ V}$	0.42	0.78	1.04		
<b>ENABLE INPUT EN</b>							
$t_{\text{on}}$	OUT voltage turn-on time	$C_L = 1\ \mu\text{F}$ , $R_L = 100\ \Omega$ , See <a href="#">Figure 14</a>				15	ms
$t_{\text{off}}$	OUT voltage turn-off time					8	
<b>CURRENT LIMIT</b>							
$t_{\text{IOS}}$	Short-circuit response time <sup>(1)</sup>	$V_{\text{IN}} = 5\text{ V}$ , $R_{\text{SHORT}} = 50\text{ m}\Omega$ , See <a href="#">Figure 15</a>	3.5 <sup>(1)</sup>			$\mu\text{s}$	
<b>FAULT</b>							
	$\overline{\text{FAULT}}$ deglitch	$\overline{\text{FAULT}}$ assertion or de-assertion due to overcurrent condition	6	9.5	13	ms	

(1) This parameter is provided for reference only and does not constitute part of TI's published device specifications for purposes of TI's product warranty

## 8.7 Typical Characteristics

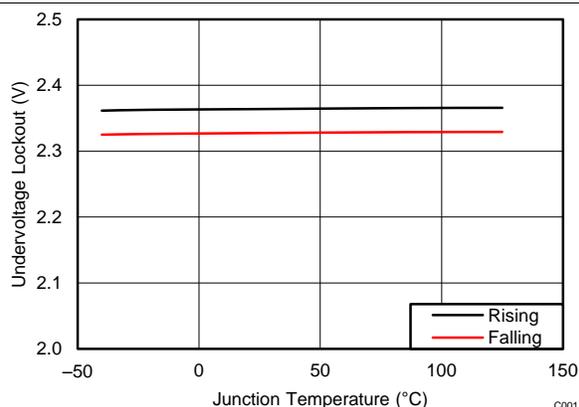


Figure 1. Under-voltage Lockout (UVLO) vs Temperature

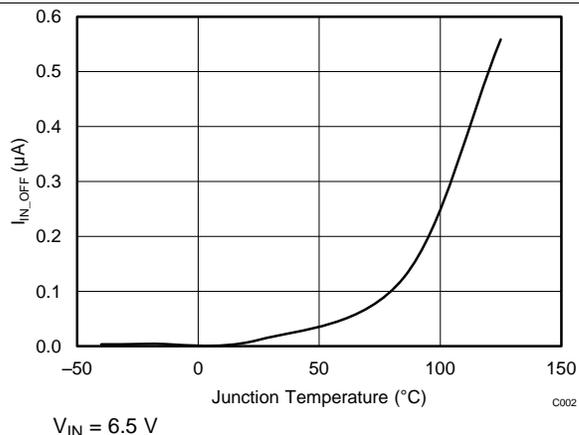


Figure 2. Supply Current, Output Disabled ( $I_{IN\_OFF}$ ) vs Temperature

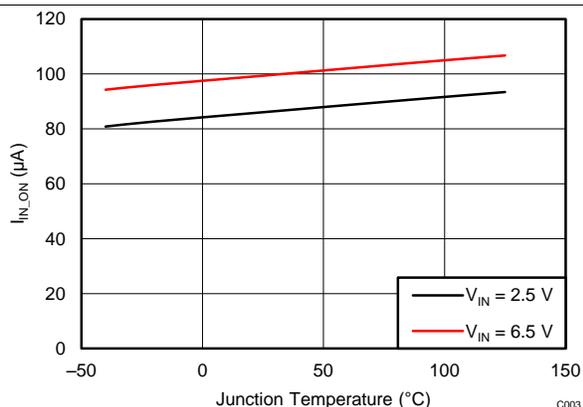


Figure 3. Supply Current, Output Enabled ( $I_{IN\_ON}$ ) vs Temperature

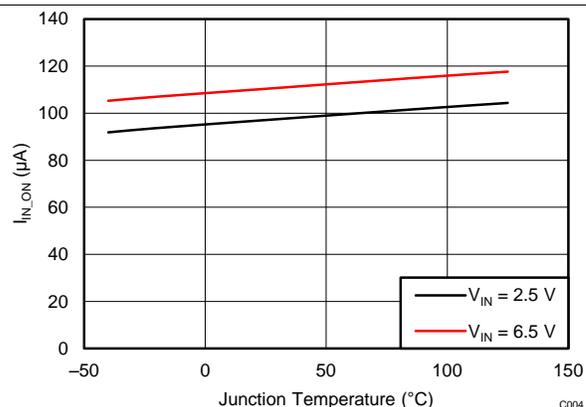


Figure 4. Supply Current, Output Enabled ( $I_{IN\_ON}$ ) vs Temperature

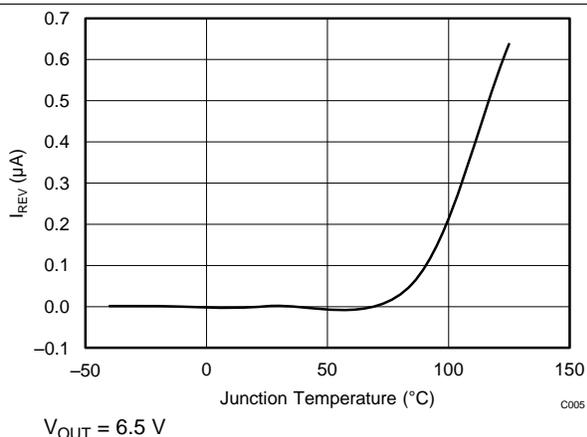


Figure 5. Reverse Leakage Current ( $I_{REV}$ ) v. Temperature

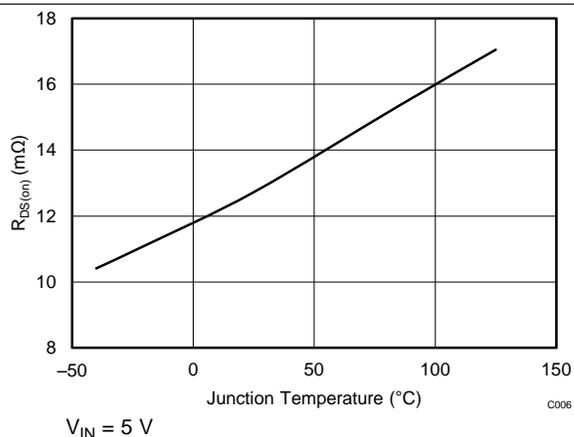


Figure 6. Input-Output Resistance ( $R_{DS(on)}$ ) vs Temperature

Typical Characteristics (continued)

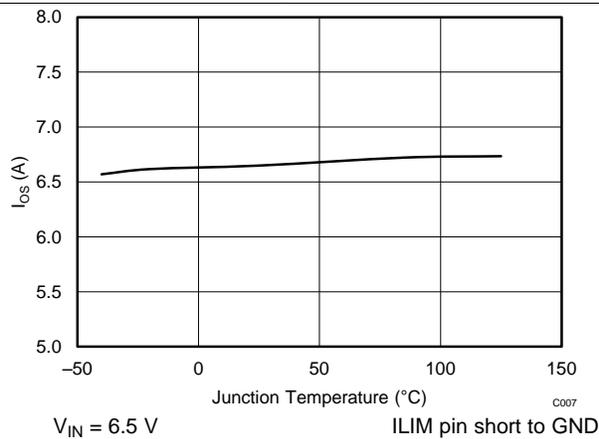


Figure 7. Short Circuit Current ( $I_{OS}$ ) vs Temperature

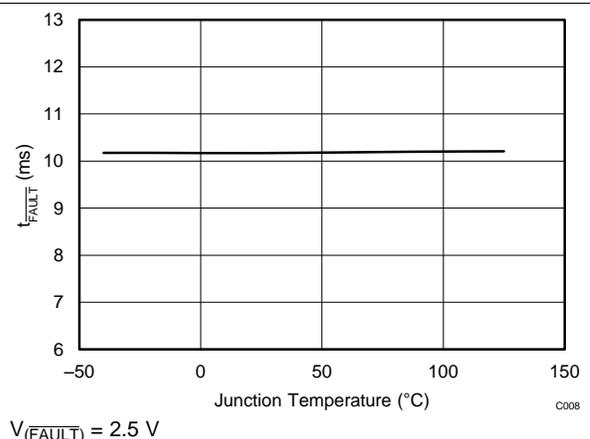


Figure 8. Deglitch Time ( $t_{FAULT}$ ) vs Temperature

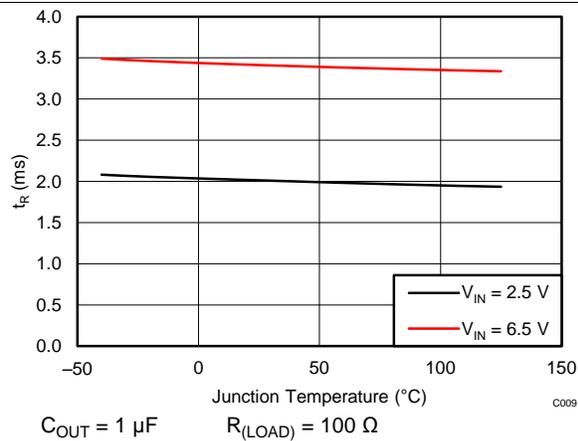


Figure 9. Output Rise Time ( $t_R$ ) vs Temperature

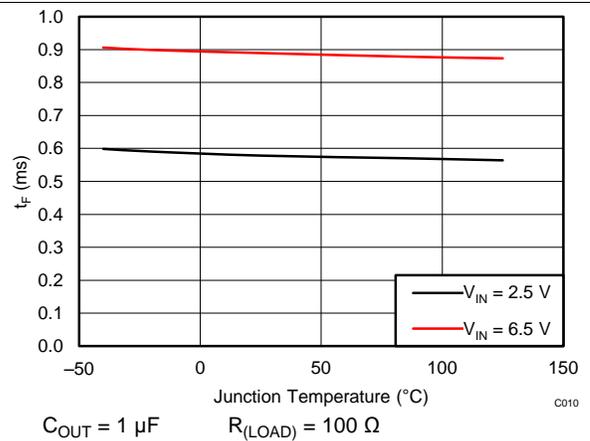


Figure 10. Output Fall Time ( $t_F$ ) vs Temperature

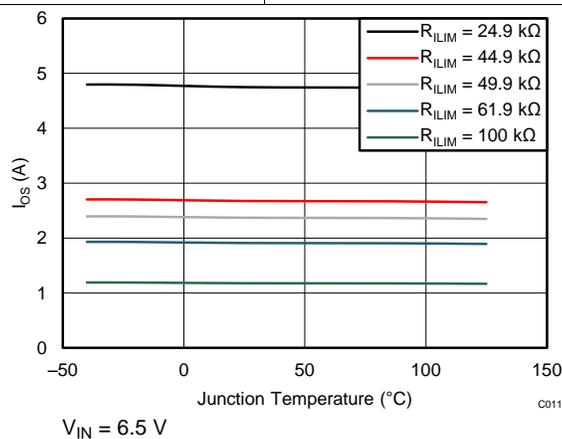


Figure 11. Short Circuit Current ( $I_{OS}$ ) vs Temperature

## 9 Parameter Measurement Information

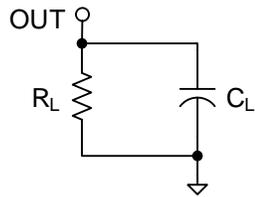


Figure 12. Output Rise/Fall time Test Load

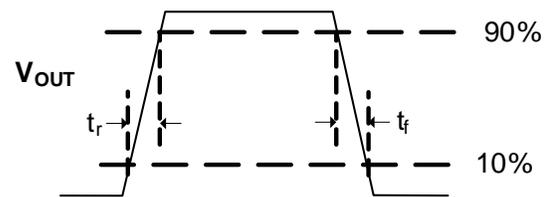


Figure 13. Power-On and Off Timing

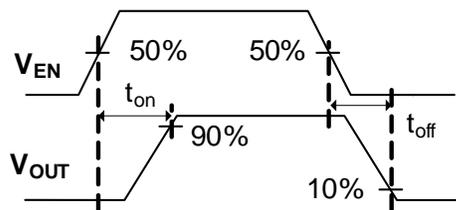


Figure 14. Enable Timing, Active High Enable

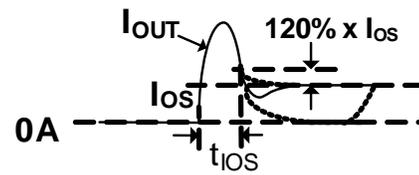


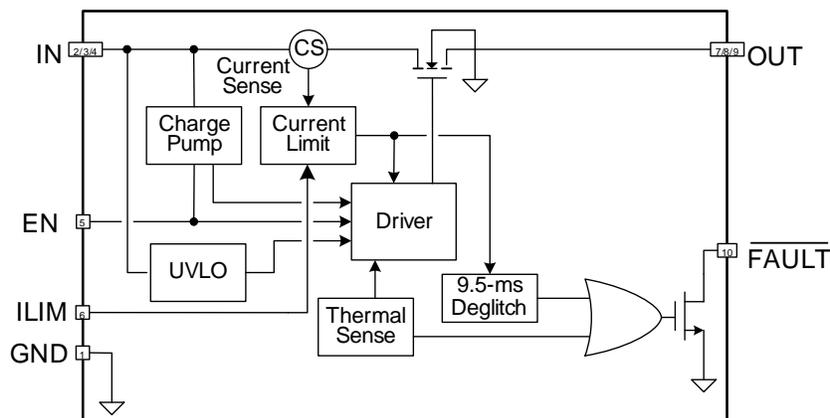
Figure 15. Output Short Circuit Parameters

## 10 Detailed Description

### 10.1 Overview

The TPS2559 is a current-limited, power-distribution switch using N-channel MOSFETs for applications where short circuits or heavy capacitive loads will be encountered. This device allows the user to program the current-limit via an external resistor and the maximum continuous output current up to 5.5 A. This device incorporates an internal charge pump and the gate drive circuitry necessary to drive the N-channel MOSFET. The charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source. The charge pump operates from input voltages as low as 2.5 V and requires little supply current. The driver controls the gate voltage of the power switch. The driver incorporates circuitry that controls the rise and fall times of the output voltage to limit large current and voltage surges and provides built-in soft-start functionality. The TPS2559 limits the output current to the programmed current-limit threshold IOS during an overcurrent or short-circuit event by reducing the charge pump voltage driving the N-channel MOSFET and operating it in the linear range of operation. The result of limiting the output current to IOS reduces the output voltage at OUT because N-channel MOSFET is no longer fully enhanced.

### 10.2 Functional Block Diagram



### 10.3 Feature Description

#### 10.3.1 Thermal Sense

The TPS2559 self protects by using two independent thermal sensing circuits that monitor the operating temperature of the power switch and disable operation if the temperature exceeds recommended operating conditions. The TPS2559 device operates in constant-current mode during an over-current condition, which increases the voltage drop across power switch. The power dissipation in the package is proportional to the voltage drop across the power switch, which increases the junction temperature during an over-current condition. The first thermal sensor (OTSD1) turns off the power switch when the die temperature exceeds 135°C (min) and the part is in current limit. Hysteresis is built into the thermal sensor, and the switch turns on after the device has cooled approximately 20°C.

The TPS2559 also has a second ambient thermal sensor (OTSD2). The ambient thermal sensor turns off the power switch when the die temperature exceeds 155°C (min) regardless of whether the power switch is in current limit and will turn on the power switch after the device has cooled approximately 20°C. The TPS2559 continues to cycle off and on until the fault is removed.

## Feature Description (continued)

### 10.3.2 Overcurrent Protection

The TPS2559 responds to overcurrent conditions by limiting their output current to  $I_{OS}$ . When an overload condition is present, the device maintains a constant output current, with the output voltage determined by  $(I_{OS} \times R_{LOAD})$ . Two possible overload conditions can occur.

The first condition is when a short circuit or partial short circuit is present when the device is powered-up or enabled. The output voltage is held near zero potential with respect to ground and the TPS2559 ramps the output current to  $I_{OS}$ . The TPS2559 limits the current to  $I_{OS}$  until the overload condition is removed or the device begins to thermal cycle (see [Figure 24](#)).

The second condition is when a short circuit, partial short circuit, or transient overload occurs while the device is enabled and powered on. The device responds to the overcurrent condition within time  $t_{IOS}$  (see [Figure 15](#)). The response speed and shape will vary with the overload level, input circuit, and rate of application. The current-limit response will vary between simply settling to  $I_{OS}$ , or turnoff and controlled return to  $I_{OS}$ . Similar to the previous case, the TPS2559 limits the current to  $I_{OS}$  until the overload condition is removed or the device begins to thermal cycle.

The TPS2559 thermal cycles if an overload condition is present long enough to activate thermal limiting in any of the above cases. The device turns off when the junction temperature exceeds 135°C (min) while in current limit. The device remains off until the junction temperature cools 20°C (typ) and then restarts. The TPS2559 cycles on/off until the overload is removed (see [Figure 25](#)).

### 10.3.3 $\overline{\text{FAULT}}$ Response

The  $\overline{\text{FAULT}}$  open-drain output is asserted (active low) during an over-current or over-temperature condition. The TPS2559 asserts the  $\overline{\text{FAULT}}$  signal until the fault condition is removed and the device resumes normal operation. The TPS2559 is designed to eliminate false  $\overline{\text{FAULT}}$  reporting by using an internal delay "deglitch" circuit for over-current (9-ms typ.) conditions without the need for external circuitry. This ensures that  $\overline{\text{FAULT}}$  is not accidentally asserted due to normal operation such as starting into a heavy capacitive load. The deglitch circuitry delays entering and leaving current-limit induced fault conditions. The  $\overline{\text{FAULT}}$  signal is not deglitched when the MOSFET is disabled due to an over-temperature condition but is deglitched after the device has cooled and begins to turn on. This unidirectional deglitch prevents  $\overline{\text{FAULT}}$  oscillation during an over-temperature event.

## 10.4 Device Functional Modes

### 10.4.1 Operation with $V_{IN}$ Undervoltage Lockout (UVLO) Control

The undervoltage lockout (UVLO) circuit disables the power switch until the input voltage reaches the UVLO turn-on threshold. Built-in hysteresis prevents unwanted on/off cycling due to input voltage droop during turn on.

### 10.4.2 Operation with EN Control

The logic enable controls the power switch and device supply current. The supply current is reduced to less than 2- $\mu\text{A}$  when a logic low is present on EN. A logic high input on EN enables the driver, control circuits, and power switch. The enable input is compatible with both TTL and CMOS logic levels.

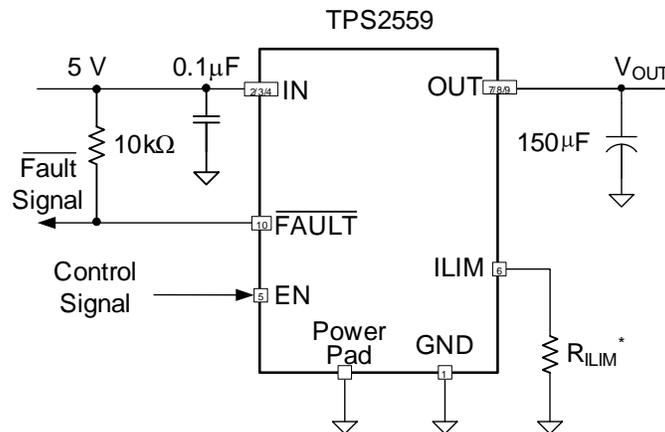
## 11 Application and Implementation

### 11.1 Application Information

The TPS2559 current limited power switch uses N-channel MOSFETs in applications requiring up to 5.5 A of continuous load current. The device enters constant-current mode when the load exceeds the current limit threshold.

The TPS2559 power switch is used to protect the up-stream power supply when the output is overloaded.

### 11.2 Typical Application



**Figure 16. Typical TPS2559 Power Switch**

Use the  $I_{OS}$  in the [Electrical Characteristics](#) table or  $I_{OS}$  in [Equation 1](#) to select the  $R_{ILIM}$ .

#### 11.2.1 Design Requirements

For this design example, use the following as the input parameters.

DESIGN PARAMETERS	EXAMPLE VALUE
Input Operation Voltage	5 V
Rating Current	3A or 4.5A
Minimum Current Limit	3A
Maximum Current Limit	5A

When choose power switch, there are some several general steps:

1. What is the power rail, 3.3 V or 5 V, and then choose the operation range of power switch can cover the power rail.
2. What is the normal operation current, for example, the maximum allowable current drawn by portable equipment for USB 2.0 port is 500mA, so the normal operation current is 500mA and the minimum current limit of power switch must exceed 500 mA to avoid false trigger during normal operation.
3. What is the maximum allowable current provided by up-stream power, and then decide the maximum current limit of power switch that must lower it to ensure power switch can protect the up-stream power when overload is encountered at the output of power switch.

#### NOTE

Choosing power switch with tighter current limit tolerance can loosen the up-stream power supply design.

## 11.2.2 Detailed Design Procedure

### 11.2.2.1 Step by Step Design Procedure

To begin the design process a few parameters must be decided upon. The designer needs to know the following:

- Normal Input Operation Voltage
- Rating Current
- Minimum Current Limit
- Maximum Current Limit

### 11.2.2.2 Input and Output Capacitance

Input and output capacitance improves the performance of the device; the actual capacitance should be optimized for the particular application. For all applications, a 0.1µF or greater ceramic bypass capacitor between IN and GND is recommended as close to the device as possible for local noise decoupling. This precaution reduces ringing on the input due to power-supply transients. Additional input capacitance may be needed on the input to reduce voltage undershoot from exceeding the UVLO of other load share one power rail with TPS2559 or overshoot from exceeding the absolute-maximum voltage of the device during heavy transient conditions. This is especially important during bench testing when long, inductive cables are used to connect the evaluation board to the bench power supply.

Output capacitance is not required, but placing a high-value electrolytic capacitor on the output pin is recommended when large transient currents are expected on the output to reduce the undershoot, which caused by the inductance of the output power bus just after a short has occurred and the TPS2559 has abruptly reduced OUT current. Energy stored in the inductance will drive the OUT voltage down and potentially negative as it discharges.

### 11.2.2.3 Programming the Current-Limit Threshold

The overcurrent threshold is user programmable via an external resistor. The TPS2559 uses an internal regulation loop to provide a regulated voltage on the ILIM pin. The current-limit threshold is proportional to the current sourced out of ILIM. The recommended 1% resistor range for  $R_{(ILIM)}$  is  $24.9\text{ k}\Omega \leq R_{(ILIM)} \leq 100\text{ k}\Omega$  to ensure stability of the internal regulation loop.

When ILIM pin short to GND (single point failure), maximum current limit is less than 8 A over temperature and process variation.

Many applications require that the minimum current limit is above a certain current level or that the maximum current limit is below a certain current level, so it is important to consider the tolerance of the overcurrent threshold when selecting a value for  $R_{(ILIM)}$ . The equations and the graph below can be used to estimate the minimum and maximum variation of the current-limit threshold for a predefined resistor value within  $R_{(ILIM)}$  is  $24.9\text{ k}\Omega \leq R_{(ILIM)} \leq 100\text{ k}\Omega$ . This variation is an approximation only and does not take into account, for example, the resistor tolerance. For examples of more-precise variation of  $I_{OS}$  refer to the current-limit section of the [Electrical Characteristics](#) table.

$$\begin{aligned}
 I_{OSmax}(\text{mA}) &= \frac{121635\text{ V}}{R_{(ILIM)}^{1.0013}\text{ k}\Omega} + 36 \\
 I_{OSnom}(\text{mA}) &= \frac{118079\text{ V}}{R_{(ILIM)}^{1.0008}\text{ k}\Omega} \\
 I_{OSmin}(\text{mA}) &= \frac{113325\text{ V}}{R_{(ILIM)}^{1.0010}\text{ k}\Omega} - 47
 \end{aligned}
 \tag{1}$$

$$24.9\text{ k}\Omega \leq R_{(ILIM)} \leq 100\text{ k}\Omega$$

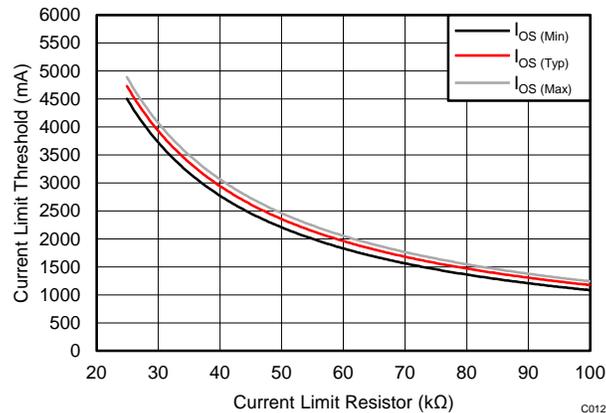


Figure 17. Current-Limit vs  $R_{(ILIM)}$

#### 11.2.2.4 Design Above a Minimum Current Limit

Some applications require that current limiting cannot occur below a certain threshold. For this example, assume that 3 A must be delivered to the load so that the minimum desired current-limit threshold is 3000 mA. Use the  $I_{OS}$  equations and Figure 17 to select  $R_{(ILIM)}$ .

$$I_{OSmin}(mA) = 3000 \text{ mA}$$

$$I_{OSmin}(mA) = \frac{113325 \text{ V}}{R_{(ILIM)}^{1.0010} \text{ k}\Omega} - 47$$

$$R_{(ILIM)}(k\Omega) = \left( \frac{113325}{I_{OS(min)} + 47} \right)^{\frac{1}{1.0010}} = \left( \frac{113325}{3000 + 47} \right)^{\frac{1}{1.0010}} = 37.06 \text{ k}\Omega \tag{2}$$

Select the closest 1% resistor less than the calculated value:  $R_{(ILIM)} = 36.5 \text{ k}\Omega$ . This sets the minimum current-limit threshold at 3016 A.

$$I_{OSmin}(mA) = \frac{113325 \text{ V}}{R_{(ILIM)}^{1.0010} \text{ k}\Omega} - 47 = \frac{113325}{(36.5 \times 1.01)^{1.0010}} - 47 = 3016 \text{ mA} \tag{3}$$

Use the  $I_{OS}$  equations, Figure 17, and the previously calculated value for  $R_{(ILIM)}$  to calculate the maximum resulting current-limit threshold.

$$I_{OSmax}(mA) = \frac{121635}{R_{(ILIM)}^{1.0013}} + 36 = \frac{121635}{(36.5 \times 0.99)^{1.0013}} + 36 = 3387 \text{ mA} \tag{4}$$

The resulting maximum current-limit threshold minimum is 3016 mA and maximum is 3387 mA with a  $36.5 \text{ k}\Omega \pm 1\%$ .

#### 11.2.2.5 Design Below a Maximum Current Limit

Some applications require that current limiting must occur below a certain threshold. For this example, assume that 5A must be delivered to the load so that the minimum desired current-limit threshold is 5000 mA. Use the  $I_{OS}$  equations and Figure 17 to select  $R_{(ILIM)}$ .

$$I_{OSmax}(mA) = 5000 \text{ mA}$$

$$I_{OSmax}(mA) = \frac{121635}{R_{(ILIM)}^{1.0013} \text{ k}\Omega} + 36$$

$$R_{(ILIM)}(k\Omega) = \left( \frac{121635}{I_{OS(max)}} \right)^{\frac{1}{1.0013}} = \left( \frac{121635}{5000 - 36} \right)^{\frac{1}{1.0013}} = 24.4 \text{ k}\Omega \tag{5}$$

Select the closest 1% resistor less than the calculated value:  $R_{(ILIM)} = 24.9 \text{ k}\Omega$ . This sets the maximum current-limit threshold at 4950 A.

$$I_{OSmax}(\text{mA}) = \frac{121635}{R_{(ILIM)}^{1.0013} \text{ k}\Omega} + 36 = \frac{121635}{(24.9 \times 0.99)^{1.0013}} + 36 = 4950 \text{ mA} \quad (6)$$

Use the  $I_{OS}$  equations, [Figure 17](#), and the previously calculated value for  $R_{(ILIM)}$  to calculate the minimum resulting current-limit threshold.

$$I_{OSmin}(\text{mA}) = \frac{113325}{R_{(ILIM)}^{1.0010}} - 47 = \frac{113325}{(24.9 \times 1.01)^{1.0010}} - 47 = 4445 \text{ mA} \quad (7)$$

The resulting minimum current-limit threshold minimum is 4445 mA and maximum is 4950 mA with a  $24.9 \text{ k}\Omega \pm 1\%$ .

### 11.2.2.6 Accounting for Resistor Tolerance

The previous sections described the selection of  $R_{(ILIM)}$  given certain application requirements and the importance of understanding the current-limit threshold tolerance. The analysis focused only on the TPS2559 is bounded by an upper and lower tolerance centered on a nominal resistance. The additional  $R_{(ILIM)}$  resistance tolerance directly affects the current-limit threshold accuracy at a system level. [Table 1](#) shows a process that accounts for worst-case resistor tolerance assuming 1% resistor values.

Step one follows the selection process outlined in the application examples above.

Step two determines the upper and lower resistance bounds of the selected resistor.

Step three uses the upper and lower resistor bounds in the  $I_{OS}$  equations to calculate the threshold limits.

It is important to use tighter tolerance resistors, that is, 0.5% or 0.1%, when precision current limiting is desired.

**Table 1. Common  $R_{(ILIM)}$  Resistor Selections**

DESIRED NOMINAL CURRENT LIMIT (mA)	IDEAL RESISTOR (k $\Omega$ )	CLOSEST 1% RESISTOR (k $\Omega$ )	RESISTOR TOLERANCE		ACTUAL LIMITS		
			1% LOW (k $\Omega$ )	1% HIGH (k $\Omega$ )	$I_{OS}$ MIN (mA)	$I_{OS}$ NOM (mA)	$I_{OS}$ MAX (mA)
1250	94.1	93.1	92.2	94	1153	1264	1348
1500	78.4	78.7	77.9	79.5	1372	1495	1588
1750	67.2	66.5	65.8	67.2	1633	1770	1874
2000	58.8	59	58.4	59.6	1847	1995	2107
2250	52.3	52.3	51.8	52.8	2090	2551	2373
2500	47.1	47.5	47	48	2306	2478	2610
2750	42.8	43.2	42.8	43.6	2541	2725	2866
3000	39.2	39.2	38.8	39.6	2805	3003	3155
3250	36.2	36.5	36.1	36.9	3016	3226	3386
3500	33.6	34	33.7	34.3	3241	3463	3633
3750	31.4	31.6	31.3	31.9	3491	3726	3907
4000	29.4	29.4	29.1	29.7	3757	4005	4197
4250	27.7	28	27.7	28.3	3947	4206	4405
4500	26.1	26.1	25.8	26.4	4238	4512	4724
4750	24.8	24.9	24.7	25.1	4445	4730	4950

### 11.2.2.7 Power Dissipation and Junction Temperature

The low on-resistance of the N-channel MOSFET allows small surface-mount packages to pass large currents. It is good design practice to estimate power dissipation and junction temperature. The below analysis gives an approximation for calculating junction temperature based on the power dissipation in the package. However, it is important to note that thermal analysis is strongly dependent on additional system level factors. Such factors include air flow, board layout, copper thickness and surface area, and proximity to other devices dissipating power. Good thermal design practice must include all system level factors in addition to individual component analysis. Begin by determining the  $r_{DS(on)}$  of the N-channel MOSFET relative to the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read  $r_{DS(on)}$  from the typical characteristics graph. Using this value, the power dissipation can be calculated by:

$$P_D = r_{DS(on)} \times I_{OUT}^2$$

Where:

$P_D$  = Total power dissipation (W)

$r_{DS(on)}$  = Power switch on-resistance ( $\Omega$ )

$I_{OUT}$  = Maximum current-limit threshold (A)

This step calculates the total power dissipation of the N-channel MOSFET.

Finally, calculate the junction temperature:

$$T_J = P_D \times \theta_{JA} + T_A$$

Where:

$T_A$  = Ambient temperature ( $^{\circ}\text{C}$ )

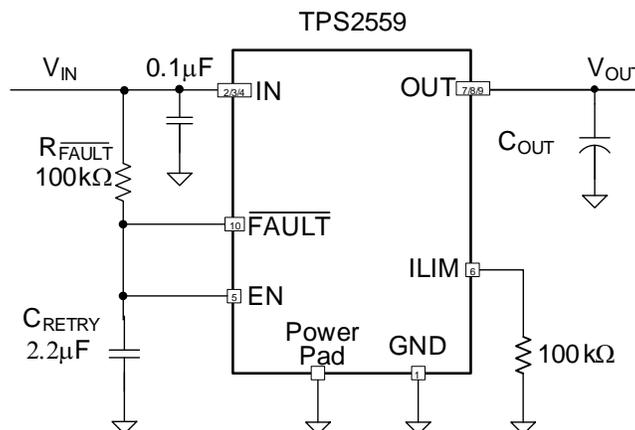
$\theta_{JA}$  = Thermal resistance ( $^{\circ}\text{C}/\text{W}$ )

$P_D$  = Total power dissipation (W)

Compare the calculated junction temperature with the initial estimate. If they are not within a few degrees, repeat the calculation using the "refined"  $r_{DS(on)}$  from the previous calculation as the new estimate. Two or three iterations are generally sufficient to achieve the desired result. The final junction temperature is highly dependent on thermal resistance  $\theta_{JA}$  and thermal resistance is highly dependent on the individual package and board layout.

### 11.2.2.8 Auto-Retry

Some applications require that an overcurrent condition disables the part momentarily during a fault condition and re-enables after a pre-set time. This *auto-retry* functionality can be implemented with an external resistor and capacitor. During a fault condition,  $\overline{\text{FAULT}}$  pulls low EN. The part is disabled when EN is pulled below the turn-off threshold, and  $\overline{\text{FAULT}}$  goes high impedance allowing  $C_{(RETRY)}$  to begin charging. The part re-enables when the voltage on EN reaches the turn-on threshold. The part will continue to cycle in this manner until the fault condition is removed. The auto-retry cycling time is determined by the resistor/capacitor time constant, TPS2559 turn on time and  $\overline{\text{FAULT}}$  deglitch time (see Figure 28).



**Figure 18. Auto-Retry Circuit**

Some applications require auto-retry functionality and the ability to enable/disable with an external logic signal. Figure 19 shows how an external logic signal can drive EN through  $R_{\text{FAULT}}$  and maintain auto-retry functionality. The resistor/capacitor time constant determines the auto-retry time-out period.

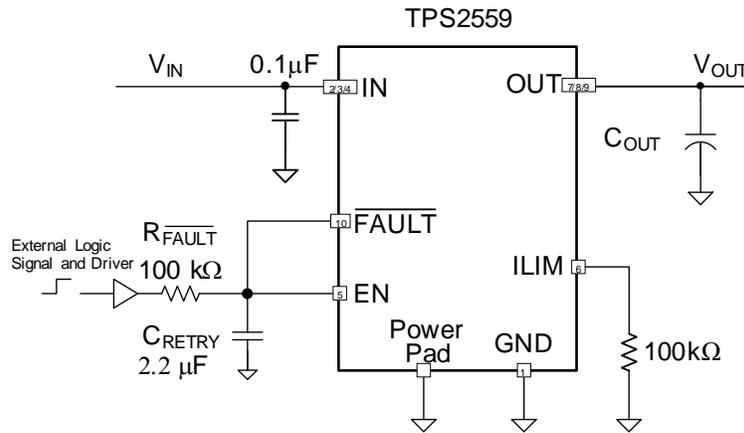


Figure 19. Auto-Retry Circuit with External EN Signal

If need to implement latch-off, refer to application report (SLVA282A).

### 11.2.2.9 Two-level Current-limit

Some applications require different current-limit thresholds depending on external system conditions. Figure 20 shows an implementation for an externally-controlled, two-level current-limit circuit. The current-limit threshold is set by the total resistance from ILIM to GND (see previously discussed [Programming the Current-Limit Threshold](#) section). A logic-level input enables/disables MOSFET Q1 and changes the current-limit threshold by modifying the total resistance from ILIM to GND (see [Figure 29](#) and [Figure 30](#)). Additional MOSFET/resistor combinations can be used in parallel to increase the number of additional current-limit levels.

#### NOTE

ILIM should never be driven directly with an external signal.

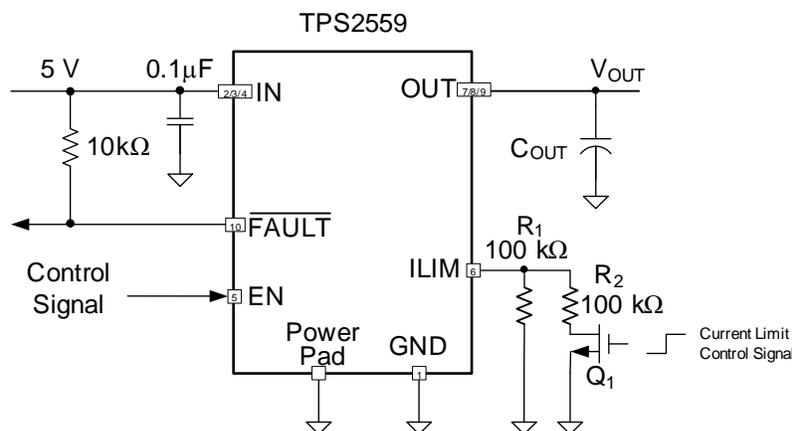


Figure 20. Two-Level Current-Limit Circuit

11.2.3 Application Curves

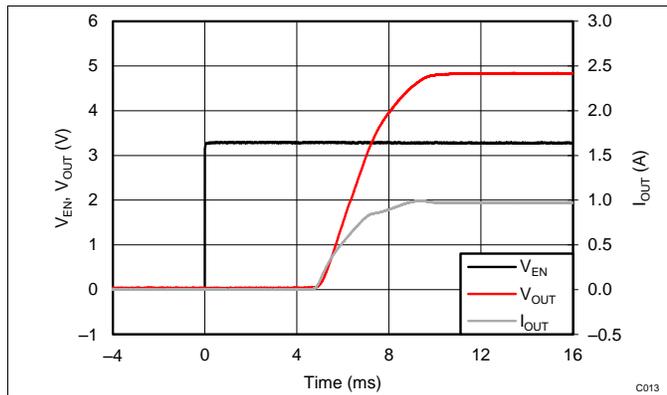


Figure 21. Output Rise with 150µF // 5Ω

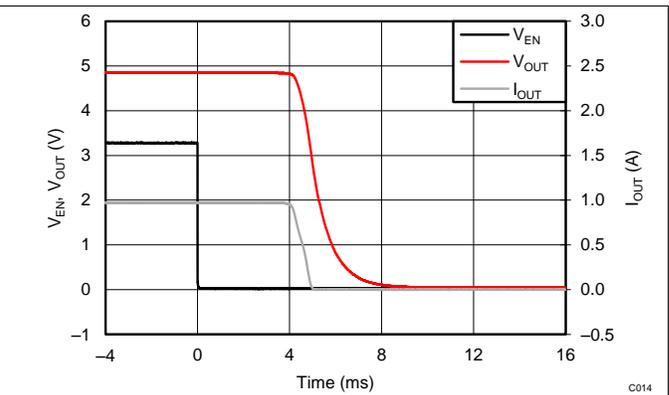


Figure 22. Output Fall with 150µF // 5Ω

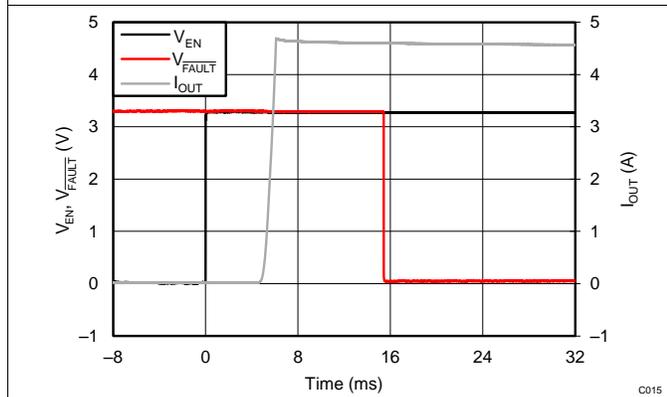


Figure 23. Enable into Output Short

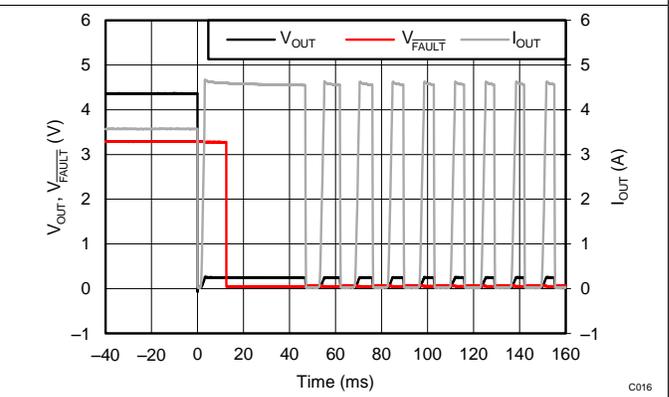


Figure 24. Full Load to Output Short Transient Response

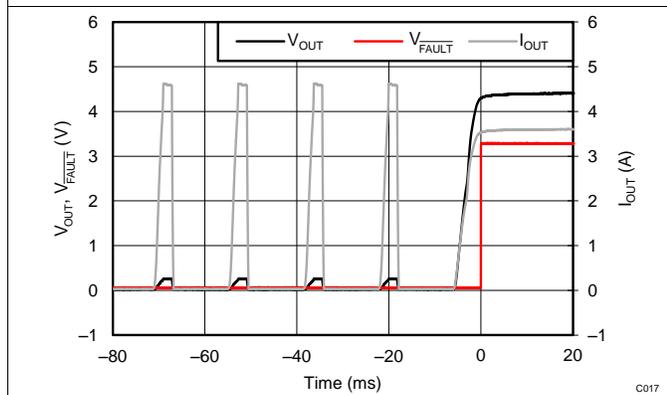


Figure 25. Output Short to Full Load Recovery Response

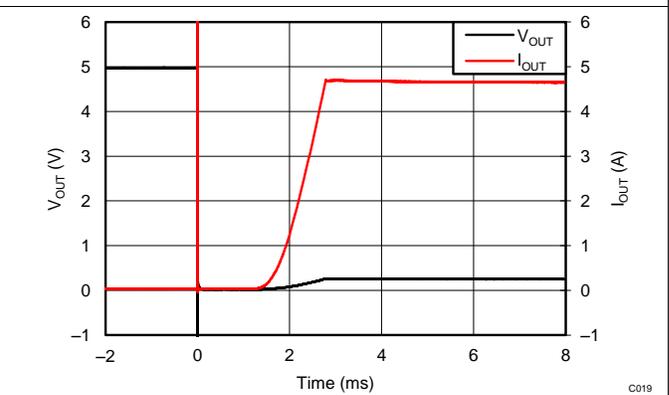


Figure 26. 50mΩ Hot-Short

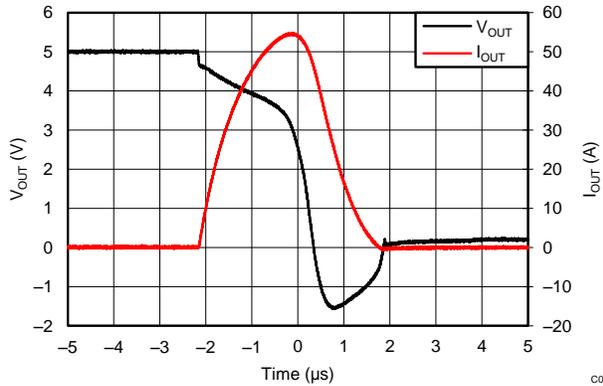


Figure 27. 50mΩ Hot-Short Response Time

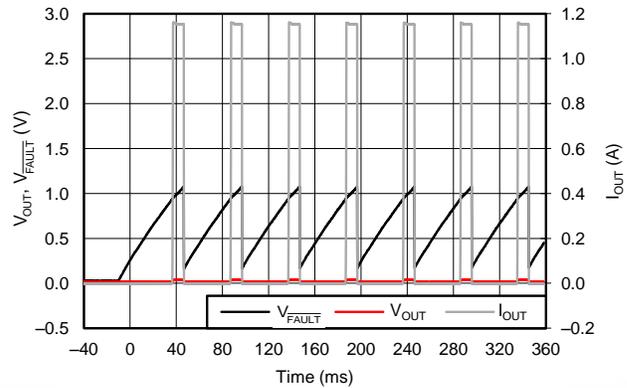


Figure 28. Auto-Retry Cycle

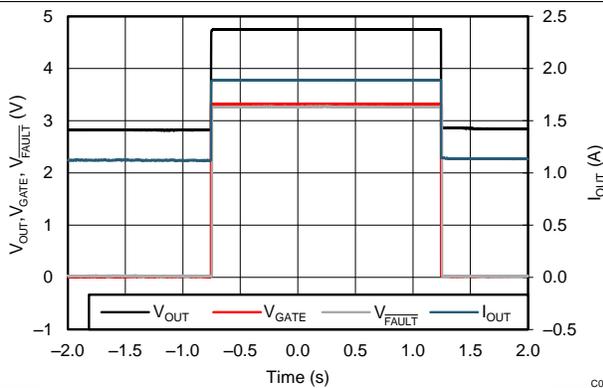


Figure 29. Two Level Current Limit with  $R_{LOAD} = 2.5 \Omega$

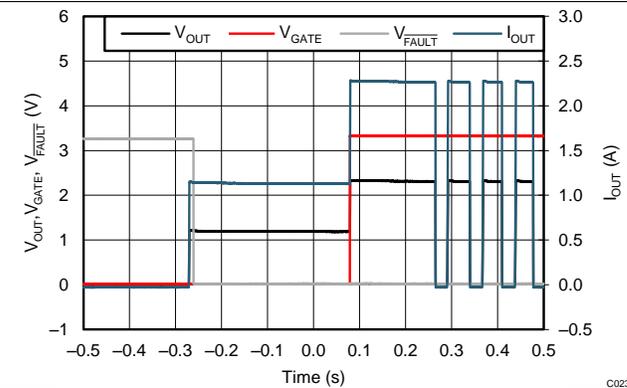


Figure 30. Two Level Current Limit with  $R_{LOAD} = 1\Omega$

## 12 Power Supply Recommendations

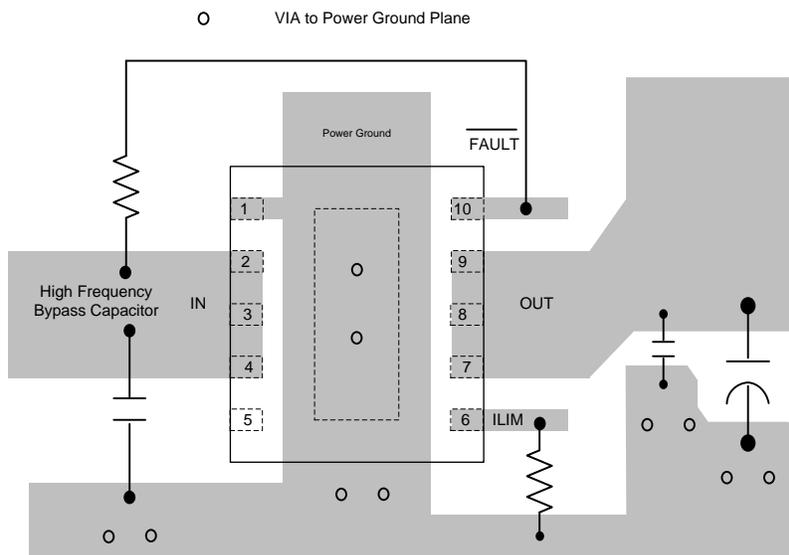
Design of the devices is for operation from an input voltage supply range of 2.5 V to 6.5 V. The current capability of the power supply should exceed the maximum current limit of the power switch.

## 13 Layout

### 13.1 Layout Guidelines

- Place the 100-nF bypass capacitor near the IN and GND pins, and make the connections using a low-inductance trace.
- Placing a high-value electrolytic capacitor and a 100-nF bypass capacitor on the output pin is recommended when large transient currents are expected on the output.
- The traces routing the  $R_{ILIM}$  resistor to the device should be as short as possible to reduce parasitic effects on the current limit accuracy.
- The PowerPAD should be directly connected to PCB ground plane using wide and short copper trace.

### 13.2 Layout Example



**Figure 31. TPS2559 Board Layout**

## 14 Device and Documentation Support

### 14.1 Trademarks

PowerPAD is a trademark of Texas Instruments.

### 14.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 14.3 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms and definitions.

## 15 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS2559DRCR	ACTIVE	VSON	DRC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2559	<a href="#">Samples</a>
TPS2559DRCT	ACTIVE	VSON	DRC	10	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2559	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

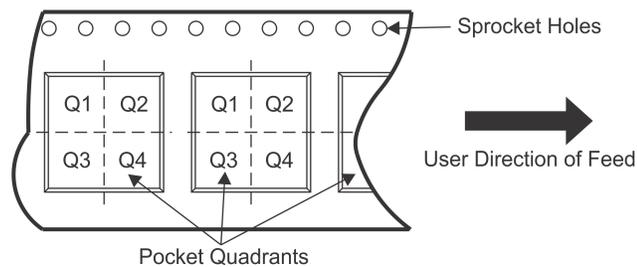
**OTHER QUALIFIED VERSIONS OF TPS2559 :**

- Automotive: [TPS2559-Q1](#)

**NOTE: Qualified Version Definitions:**

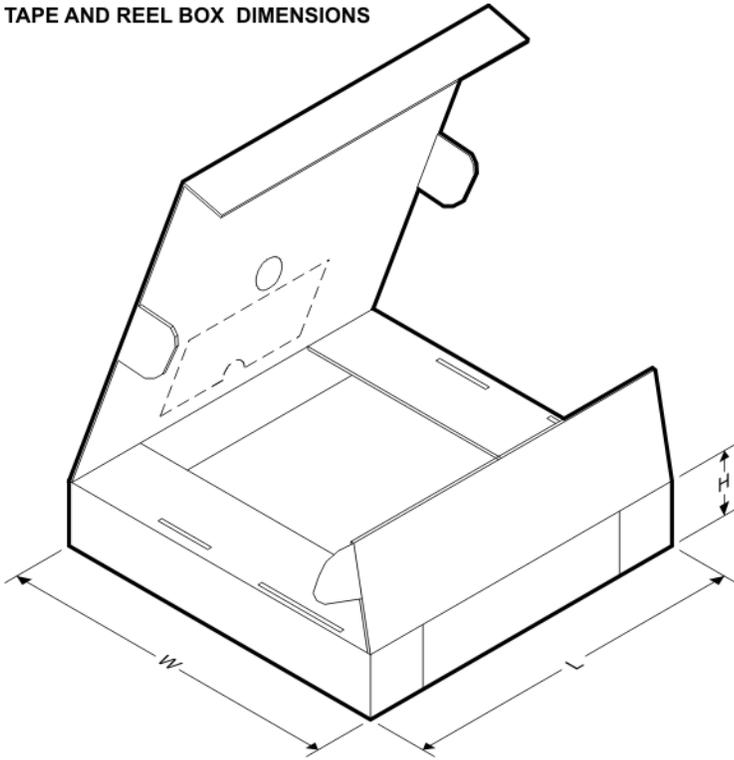
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2559DRCR	VSON	DRC	10	3000	180.0	12.5	3.3	3.3	1.1	8.0	12.0	Q2
TPS2559DRCR	VSON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS2559DRCT	VSON	DRC	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS2559DRCT	VSON	DRC	10	250	180.0	12.5	3.3	3.3	1.1	8.0	12.0	Q2

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

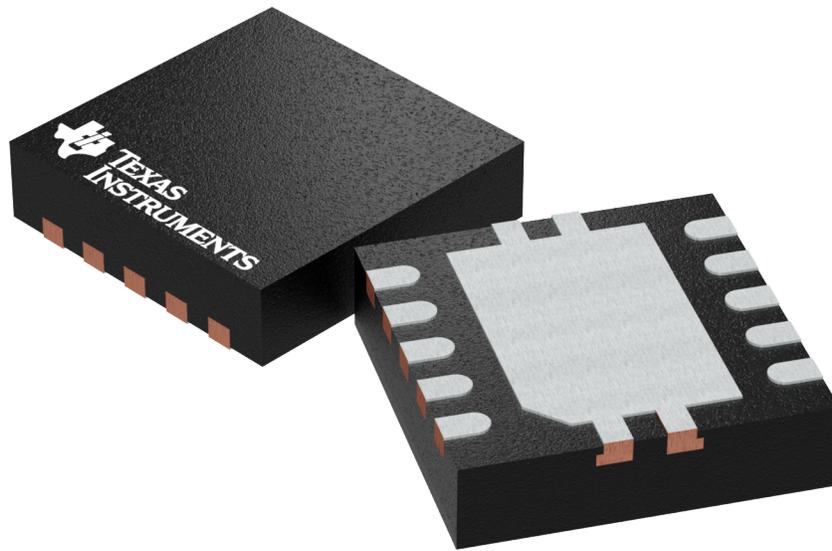
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2559DRCR	VSON	DRC	10	3000	338.0	355.0	50.0
TPS2559DRCR	VSON	DRC	10	3000	367.0	367.0	35.0
TPS2559DRCT	VSON	DRC	10	250	210.0	185.0	35.0
TPS2559DRCT	VSON	DRC	10	250	338.0	355.0	50.0

## GENERIC PACKAGE VIEW

DRC 10

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

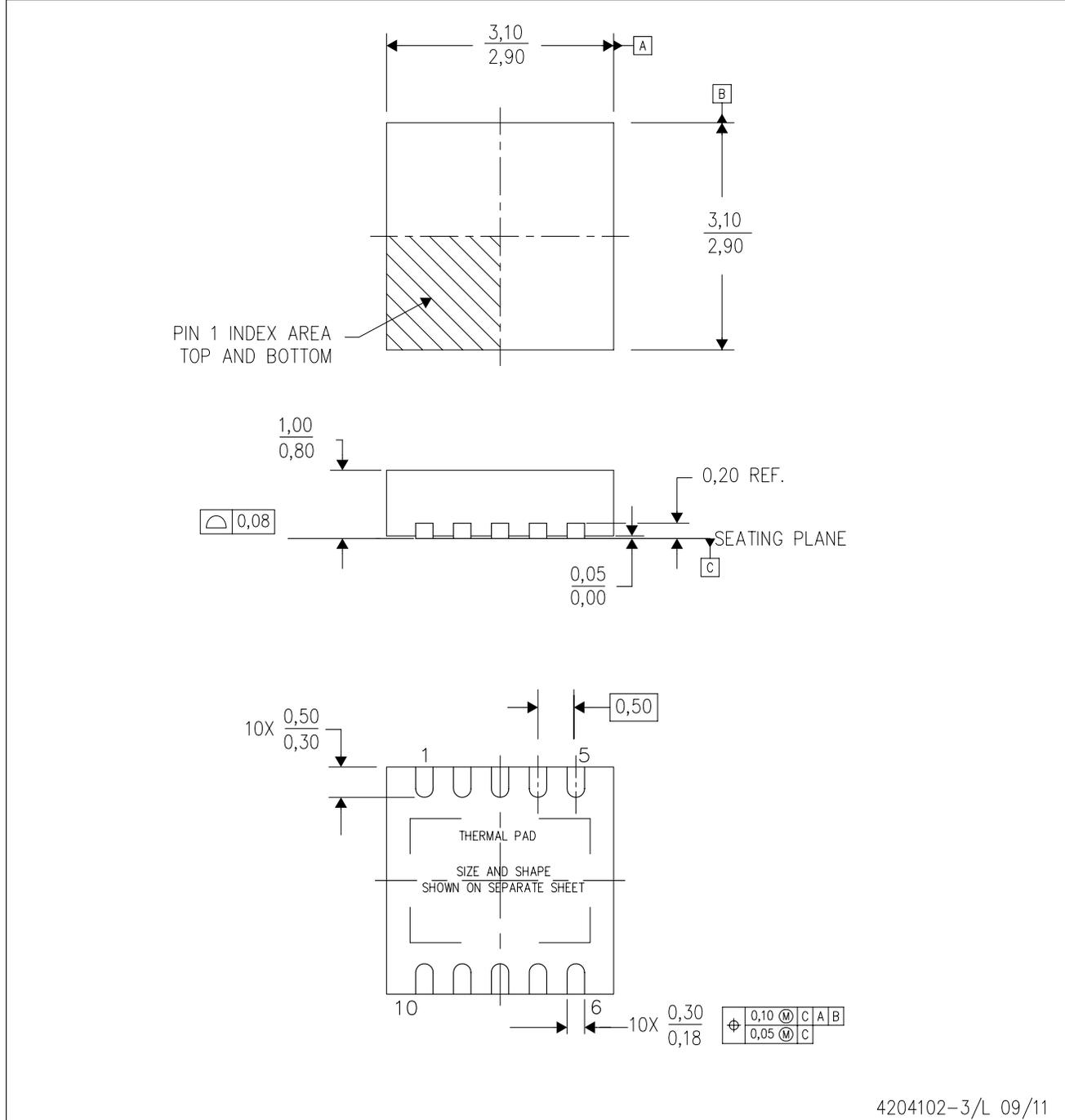


Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

4204102-3/M

DRC (S-PVSON-N10)

PLASTIC SMALL OUTLINE NO-LEAD



4204102-3/L 09/11

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - This drawing is subject to change without notice.
  - Small Outline No-Lead (SON) package configuration.
  - The package thermal pad must be soldered to the board for thermal and mechanical performance, if present.
  - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions, if present

# THERMAL PAD MECHANICAL DATA

DRC (S-PVSON-N10)

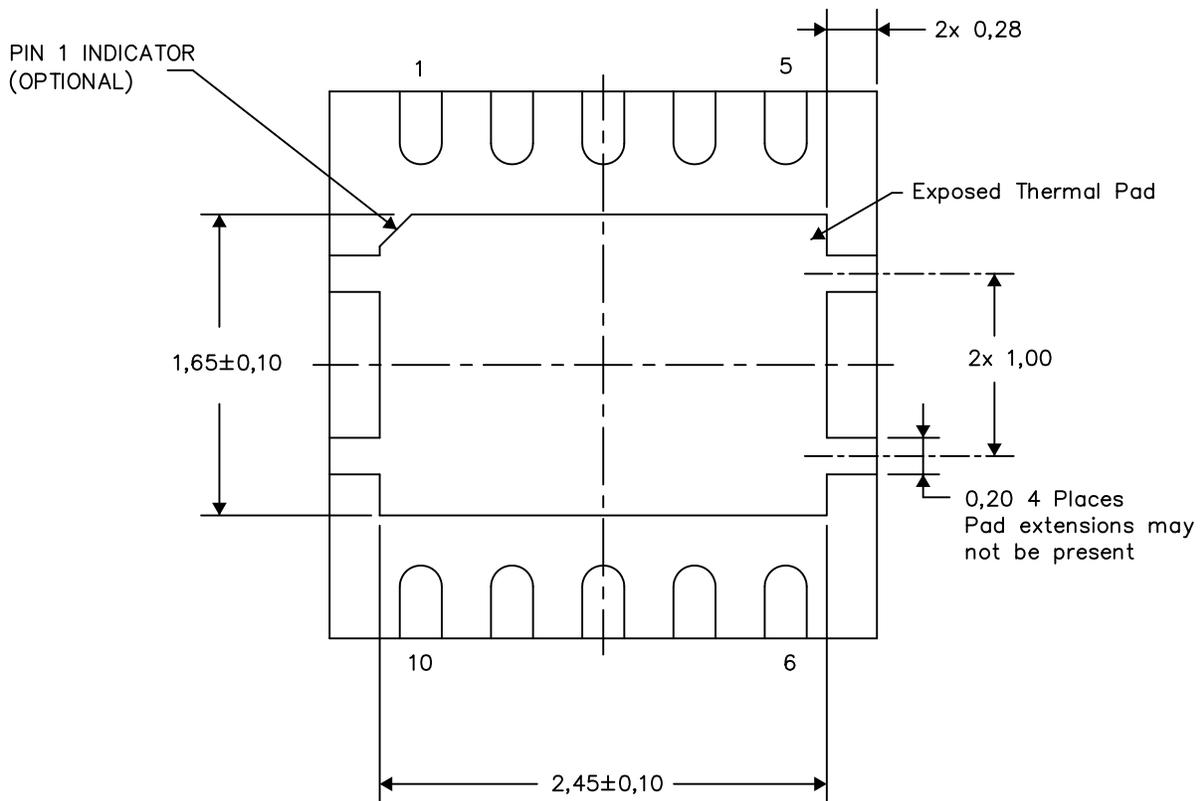
PLASTIC SMALL OUTLINE NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

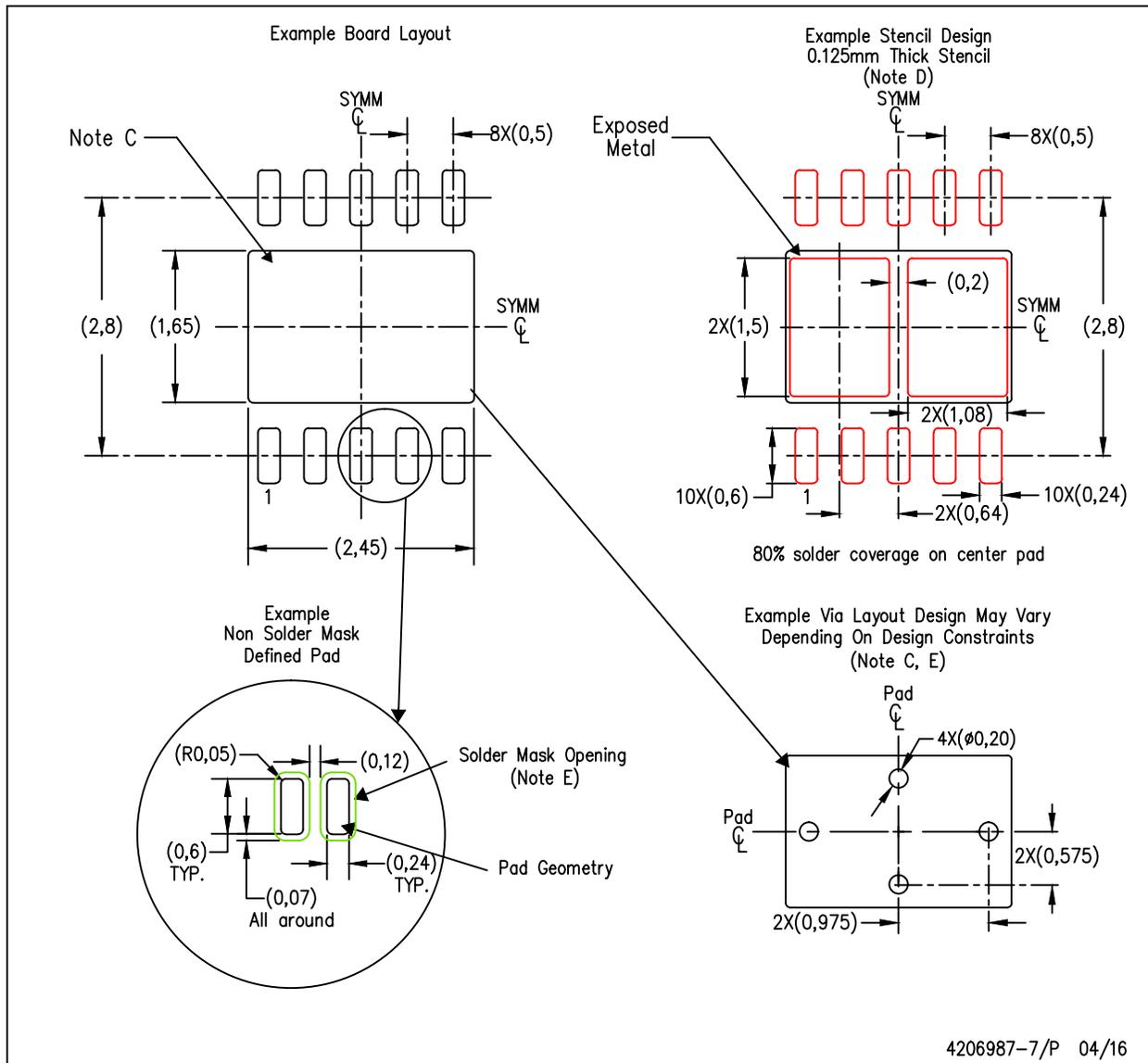
Exposed Thermal Pad Dimensions

4206565-10/Y 08/15

NOTE: A. All linear dimensions are in millimeters

DRC (S-PVSON-N10)

PLASTIC SMALL OUTLINE NO-LEAD



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads and via tenting recommendations for any larger diameter vias placed in the thermal pad.

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